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**Nanotechnologies — Structural  
characterization of graphene —**

Part 1:  
**Graphene from powders and  
dispersions**

*Nanotechnologies — Caractérisation structurelle du graphène —  
Partie 1: Graphène issu de poudres et de dispersions*





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## Foreword

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The procedures used to develop this document and those intended for its further maintenance are described in the ISO/IEC Directives, Part 1. In particular, the different approval criteria needed for the different types of document should be noted. This document was drafted in accordance with the editorial rules of the ISO/IEC Directives, Part 2 (see [www.iso.org/directives](http://www.iso.org/directives) or [www.iec.ch/members\\_experts/refdocs](http://www.iec.ch/members_experts/refdocs)).

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For an explanation of the voluntary nature of standards, the meaning of ISO specific terms and expressions related to conformity assessment, as well as information about ISO's adherence to the World Trade Organization (WTO) principles in the Technical Barriers to Trade (TBT) see [www.iso.org/iso/foreword.html](http://www.iso.org/iso/foreword.html). In the IEC, see [www.iec.ch/understanding-standards](http://www.iec.ch/understanding-standards).

This document was prepared jointly by Technical Committee ISO/TC 229, *Nanotechnologies*, and Technical Committee IEC/TC 113, *Nanotechnology for electrotechnical products and systems*.

A list of all parts in the ISO/IEC 21356 series can be found on the ISO and IEC websites.

Any feedback or questions on this document should be directed to the user's national standards body. A complete listing of these bodies can be found at [www.iso.org/members.html](http://www.iso.org/members.html) and [www.iec.ch/national-committees](http://www.iec.ch/national-committees).

## Introduction

Due to the many superlative properties of graphene and related 2D materials, there are many application areas where these nanomaterials could be disruptive, areas such as flexible electronics, nanocomposites, sensing, filtration membranes and energy storage.

There are barriers to commercialisation that are impeding the progress of products containing graphene, which need to be overcome. One of these crucial barriers is answering the question “What is my material?”. End-users of the raw materials containing graphene should be able to rely on the advertised properties of the commercial graphene on the global market, instilling trust and allowing worldwide trade. Reliable and repeatable measurement protocols are required to address this challenge.

This document provides a set of flow-charts for analysts to follow in order to determine the structural properties of graphene from powders and liquid dispersions (suspensions). Initially, a quick check should be undertaken to determine if graphene and/or graphitic material is present. If it is, then further detailed analysis is required to determine if the samples contain a mixture of single-layer graphene, bilayer graphene, few-layer graphene, graphene nanoplatelets and graphite particles. Depending on the methods used, the samples are typically analysed after deposition on a substrate. The document describes how to assess what measurements are required depending on the type of sample and includes decision trees and flow diagrams to aid the user. This document describes a selected set of measurands that are needed, namely:

- a) the number of layers/thickness of the flakes;
- b) the lateral dimensions of flakes;
- c) layer alignment;
- d) the level of disorder;
- e) the estimated number fraction of graphene or few-layer graphene;
- f) the specific surface area of the powder containing graphene.

The above physical properties of the material can change during its processing and lifetime, for example, the samples can become more agglomerated, obtain different surface functionalities. The above measurand list for the initial material defines their inherent characteristics that, along with the chosen manufacturing processes, will determine the performance of real-world products. Generally, different material properties can be important in different application areas, depending on the functional role of the material.

The document provides methods for structural characterization of individual flakes of graphene, bilayer graphene, graphene nanoplatelets and graphite particles isolated from powders and/or liquid dispersions. It does not provide methods for determination of whether the powders and/or dispersions are composed solely of these materials. No recommendation is provided as to when or how often to measure samples, although it is not expected this would be for every batch of the same material. It is up to the user to determine when, how often and which characterization routes described in this document to take. As with all microscopical investigations, care is needed in drawing statistical conclusions dependant on representative sampling.

A set of annexes provide example protocols on how to prepare and analyse the samples, sources of uncertainty and how to analyse the data. The methods used are Raman spectroscopy, scanning electron microscopy (SEM), atomic force microscopy (AFM), transmission electron microscopy (TEM) and the BET (Brunauer–Emmett–Teller) method.



# Nanotechnologies — Structural characterization of graphene —

## Part 1: Graphene from powders and dispersions

### 1 Scope

This document specifies the sequence of methods for characterizing the structural properties of graphene, bilayer graphene and graphene nanoplatelets from powders and liquid dispersions using a range of measurement techniques typically after the isolation of individual flakes on a substrate. The properties covered are the number of layers/thickness, the lateral flake size, the level of disorder, layer alignment and the specific surface area. Suggested measurement protocols, sample preparation routines and data analysis for the characterization of graphene from powders and dispersions are given.

### 2 Normative references

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

ISO/TS 80004-1:2015, *Nanotechnologies — Vocabulary — Part 1: Core terms*

ISO/TS 80004-2:2015, *Nanotechnologies — Vocabulary — Part 2: Nano-objects*

ISO/TS 80004-6:2021, *Nanotechnologies — Vocabulary — Part 6: Nano-object characterization*

ISO/TS 80004-13:2017, *Nanotechnologies — Vocabulary — Part 13: Graphene and related two-dimensional (2D) materials*